SWITCHMODE ™ **Power Rectifier**

Features and Benefits

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capacity
- 150°C Operating Junction Temperature
- 25 A Total (12.5 A Per Diode Leg)
- Pb-Free Packages are Available*

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

Mechanical Characteristics

- Case: Epoxy, Molded
- Epoxy Meets UL 94, V-0 @ 0.125 in
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperatures for Soldering Purposes: 260°C Max. for 10 Seconds
- ESD Rating: Human Body Model 3B

Machine Model C

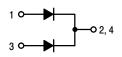
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

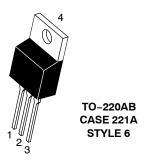


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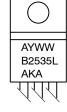
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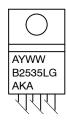
SCHOTTKY BARRIER RECTIFIER 25 AMPERES, 35 VOLTS





MARKING DIAGRAMS





A = Assembly Location

Y = Year
WW = Work Week
B2535L = Device Code
G = Pb-Free Package
AKA = Polarity Designator

ORDERING INFORMATION

| Device | Package | Shipping |
|-------------|---------------------|---------------|
| MBR2535CTL | TO-220 | 50 Units/Rail |
| MBR2535CTLG | TO-220 (Pb-Free) | 50 Units/Rail |

MAXIMUM RATINGS (Per Leg)

| Rating | | Value | Unit |
|--|--|-------------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 35 | V |
| Average Rectified Forward Current (T _C = 142°C per Diode) (T _C = 142°C per Device) | I _{F(AV)} | 12.5 25 | A |
| Peak Repetitive Forward Current, per Leg (Sq Wave, 20 kHz, T _C = 139°C) | I _{FRM} | 25 | Α |
| Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions, Halfwave, Single Phase, 60 Hz) | I _{FSM} | 150 | Α |
| Peak Repetitive Reverse Surge Current (2.0 μs, 1.0 kHz) | I _{RRM} | 1.0 | Α |
| Storage Temperature Range | T _{stg} | -65 to +150 | °C |
| Operating Junction Temperature (Note 1) | | -65 to +150 | °C |
| Voltage Rate of Change (Rated V _R) | dv/dt | 10,000 | V/μs |
| Controlled Avalanche Energy | W _{aval} | 20 | mJ |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

| Characteristic | Conditions | Symbol | Max | Unit |
|---|------------|-----------------|------|------|
| Maximum Thermal Resistance, Junction-to-Case | Min. Pad | $R_{\theta JC}$ | 2.0 | °C/W |
| Maximum Thermal Resistance, Junction-to-Ambient | Min. Pad | $R_{\theta JA}$ | 75.0 | |

ELECTRICAL CHARACTERISTICS

| Characteristic | Symbol | Min | Typical | Max | Unit |
|---|----------------|-------------|----------------------|----------------------|------|
| Instantaneous Forward Voltage (Note 2) ($i_F = 25 \text{ Amps}$, $T_j = 25^{\circ}\text{C}$) ($i_F = 12.5 \text{ Amps}$, $T_j = 25^{\circ}\text{C}$) ($i_F = 12.5 \text{ Amps}$, $T_j = 125^{\circ}\text{C}$) | v _F | - - - | 0.51 0.41 0.33 | 0.55 0.47 0.41 | V |
| Instantaneous Reverse Current (Note 2) (Rated dc Voltage, Tj = 25°C) (Rated dc Voltage, Tj = 125°C) | i _R | - - | 0.8 300 | 5.0 500 | mA |

^{2.} Pulse Test: Pulse Width = 300 $\mu s,$ Duty Cycle \leq 2.0%.

^{1.} The heat generated must be less than the thermal conductivity from Junction–to–Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

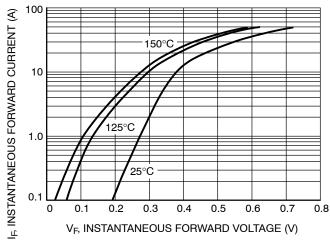


Figure 1. Typical Forward Voltage

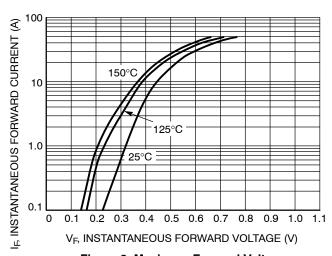


Figure 2. Maximum Forward Voltage

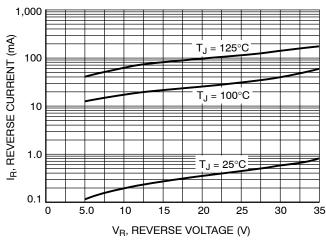


Figure 3. Typical Reverse Current, Per Leg

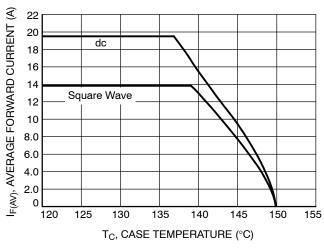


Figure 4. Current Derating, Case, Per Leg

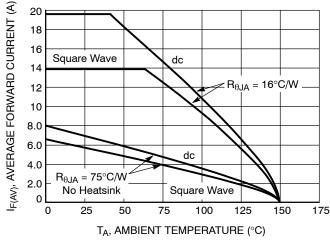


Figure 5. Current Derating, Ambient, Per Leg

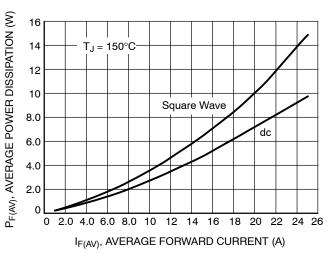
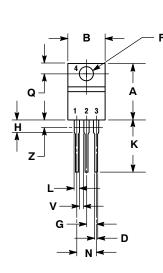
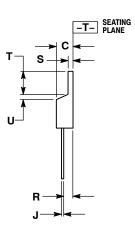


Figure 6. Forward Power Dissipation

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AF**





- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

| | INCHES | | MILLIMETERS | | |
|-----|--------|-------|-------------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.570 | 0.620 | 14.48 | 15.75 | |
| В | 0.380 | 0.405 | 9.66 | 10.28 | |
| С | 0.160 | 0.190 | 4.07 | 4.82 | |
| D | 0.025 | 0.035 | 0.64 | 0.88 | |
| F | 0.142 | 0.161 | 3.61 | 4.09 | |
| G | 0.095 | 0.105 | 2.42 | 2.66 | |
| Н | 0.110 | 0.155 | 2.80 | 3.93 | |
| J | 0.014 | 0.025 | 0.36 | 0.64 | |
| K | 0.500 | 0.562 | 12.70 | 14.27 | |
| L | 0.045 | 0.060 | 1.15 | 1.52 | |
| N | 0.190 | 0.210 | 4.83 | 5.33 | |
| Q | 0.100 | 0.120 | 2.54 | 3.04 | |
| R | 0.080 | 0.110 | 2.04 | 2.79 | |
| S | 0.045 | 0.055 | 1.15 | 1.39 | |
| T | 0.235 | 0.255 | 5.97 | 6.47 | |
| U | 0.000 | 0.050 | 0.00 | 1.27 | |
| ٧ | 0.045 | | 1.15 | | |
| Z | | 0.080 | | 2.04 | |

STYLE 6: PIN 1. ANODE

- 2. CATHODE
- 3 ANODE CATHODE

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